

10/562071

IAP20 Rec'd DEC 22 2005
APPLICATION DATA SHEET

APPLICATION INFORMATION

Application Number::

Filing Date::

December 22, 2005

Application type::

Regular

Subject Matter::

Utility

Title::

High-Heat-Resistant Semiconductor
Device

Attorney Docket No.::

102253.57240US

Request for Early Publication?::

No

Request for Non-Publication?::

No

Suggested Drawing Figure::

1

Total Drawing Sheets::

6

Small Entity?::

No

Petition included?::

No

APPLICANT INFORMATION

Applicant one Authority Type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given name::	Yoshitaka
Family name::	SUGAWARA
Residence	Osaka, Japan
Street of mailing address::	c/o The Kansai Electric Power Co., Inc. 6-16, Nakanoshima 3-chome, Kita-ku,
City of mailing address::	Osaka-shi
State or Province of mailing address::	Osaka
Country of mailing address::	Japan
Postal or Zip Code of mailing address::	530-8270

CORRESPONDENCE INFORMATION

Correspondence customer number:: 23911

REPRESENTATIVE INFORMATION

Representative customer number:: 23911

DOMESTIC PRIORITY INFORMATION

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This application	is a 371 National Stage of	PCT/JP2004/010315	07/20/2004

FOREIGN PRIORITY INFORMATION

Country::	Application Number::	Filing Date::	Priority Claimed::
JP	2003-283057	07/30/2003	Yes

ASSIGNEE INFORMATION

Assignee Name:: The Kansai Electric Power Co., Inc.
Street of mailing address:: 6-16, Nakanoshima 3-chome, Kita-ku,
City of mailing address:: Osaka-shi,
State or Province of Mailing Address:: Osaka
Country of Mailing Address:: Japan
Postal or Zip Code of mailing address:: 530-8270